

## W005M THRU W10M

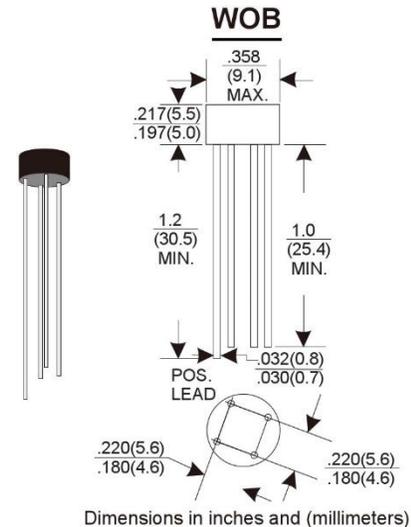
Voltage Range 50 to 1000 V  
Current 1.0 Ampere

### FEATURES

- Glass passivated chip
- High surge forward current capability
- Reliable low cost construction utilizing molded plastic technique
- Lead tin plated copper
- Meet UL flammability classification 94V-0

### MECHANICAL DATA

- Polarity: Symbol marked on body
- Mounting position: Any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Parameter	Symbol	W 005M	W 01M	W 02M	W 04M	W 06M	W 08M	W 10M	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current @ $T_A=25^\circ\text{C}$	$I_{F(AV)}$	1.0							A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	45							A
Rating for fusing ( $t < 8.3$ ms)	$I^2t$	8.4							$\text{A}^2\text{s}$
Maximum instantaneous forward drop per diode @ $I_F=1.0\text{A}$	$V_F$	1.1							V
Maximum DC reverse current at rated DC blocking voltage per diode	$I_R$	10 500							$\mu\text{A}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150							$^\circ\text{C}$

**RATINGS AND CHARACTERISTICS CURVES**

Fig.1 - Forward Current Derating Curve

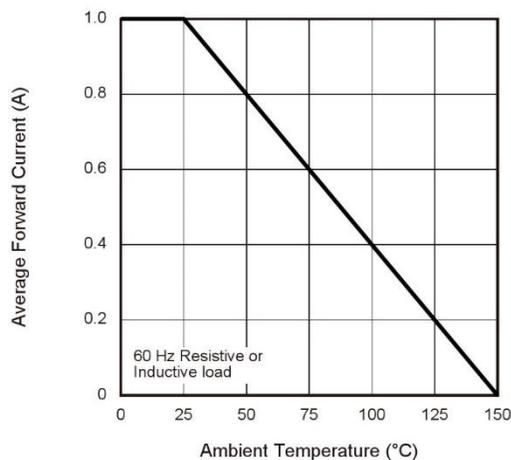


Fig.2 - Maximum Non-Repetitive Peak Forward Surge Current

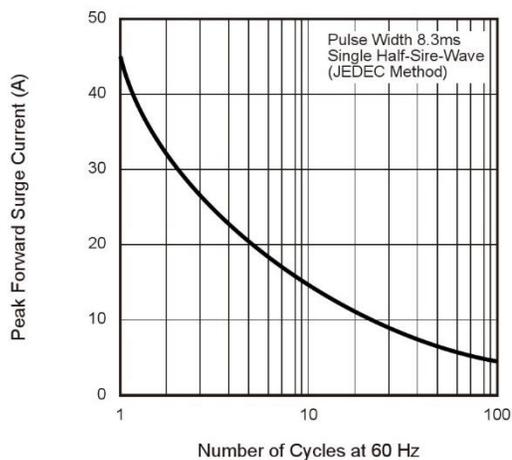


Fig.3 - Typical Instantaneous Forward Characteristics

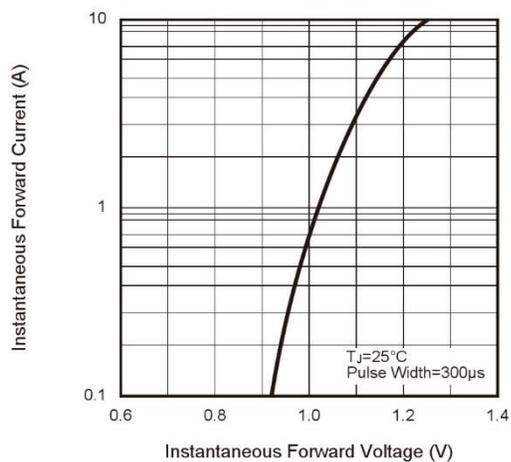
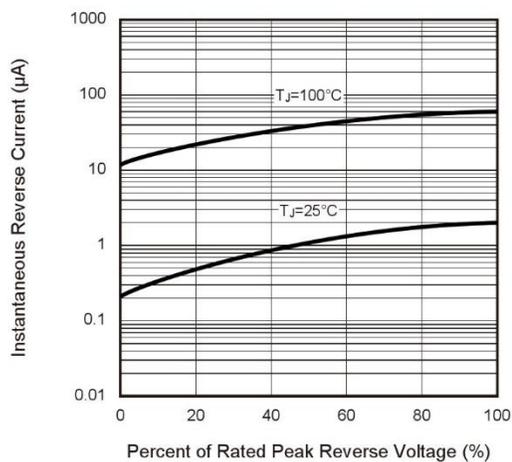


Fig.4 - Typical Reverse Leakage Characteristics



**ORDER INFORMATION**

Part Number	Marking Code	Package	Quantity	Delivery Mode
WxxM	1WxxG	WOB	1,000	Box

Note : "xx" defines voltage from 50V(W005M) to 1000V(W10M)